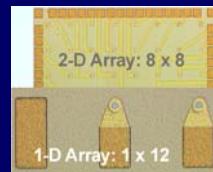




VERTILAS®

Demonstration of
10.3 Gbps 1310 nm InP BTJ-VCSEL
for 10GE Applications



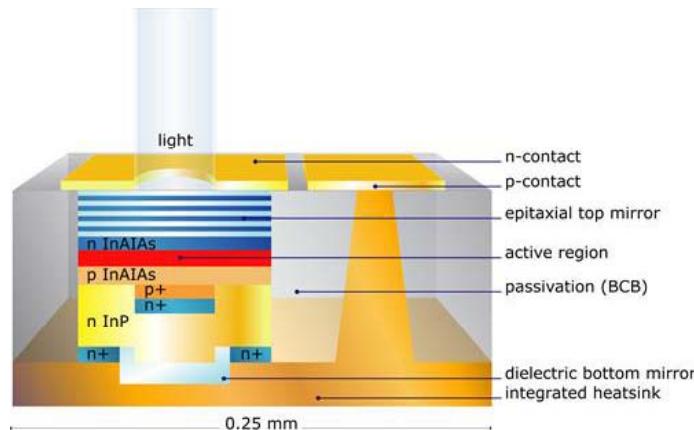
VERTILAS' Unique Technology Offers Major Advantages

VERTILAS' Advantages – VCSELs from $1.3\mu m$ to $> 2\mu m$

**Very low
power dissipation**

Cost effective

**Very high
performance**



**Very high
integration**

BTJ – Buried Tunnel Junction – made by VERTILAS

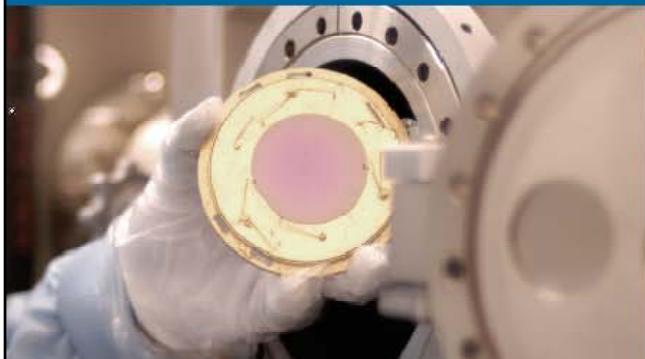




VERTILAS®

VCSEL Diodes for Data Communications LAN, SAN, MAN, FTTx, Interconnect

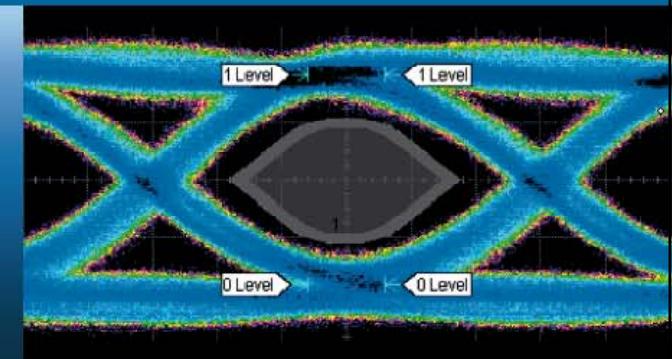
1310 nm, 1490 nm, 1550 nm, CWDM



InP VCSEL



Packaging Options



10 Gbps Performance

High Data Rate Laser Diodes from 1 Gbps to 10 Gbps

Ultra Low Power Consumption of 25 mW (typ.)

Enabling 10 Gbps Optical Modules with $P_{diss} < 750$ mW

InP VCSEL 1310 nm in LC TOSA 10.3 Gbps and 12.5 Gbps

Product Information

Single-Mode VCSEL	10 Gbps
1310 nm	LC TOSA
VL-1310-10G-P2-LC	TO-46



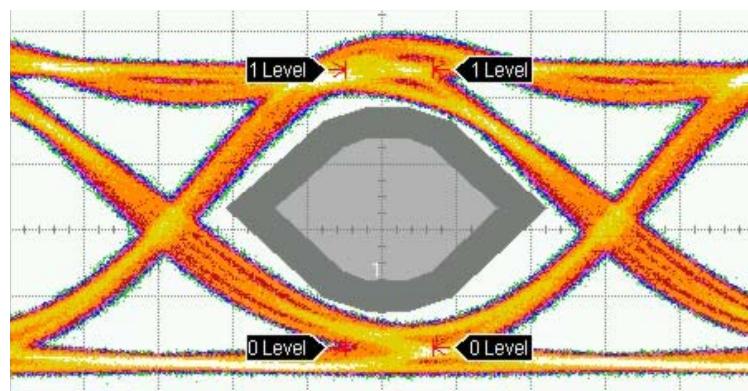
Key Features

- 1310 nm single-mode VCSEL in LC receptacle
- TO-46 form factor
- Operating temperature:
 - -20 to +70 °C,
 - extended -40 to +85°C
- High data-rate modulation: 10.3 Gbps and 12.5 Gbps
- Low power dissipation of typ. 30 mW
- Low drive currents
- Low threshold voltage
- Integrated monitoring diode



Eye Diagram InP VCSEL 1310 nm (10.3 Gbps, ER 5.4 dB)

10.3 Gbps Eye Diagram



BER Measurement SSMF 10 km

